

Joint ITU-T/IEEE Workshop on Next Generation Optical Access Systems

Optical Component Technology Review and Future Trends

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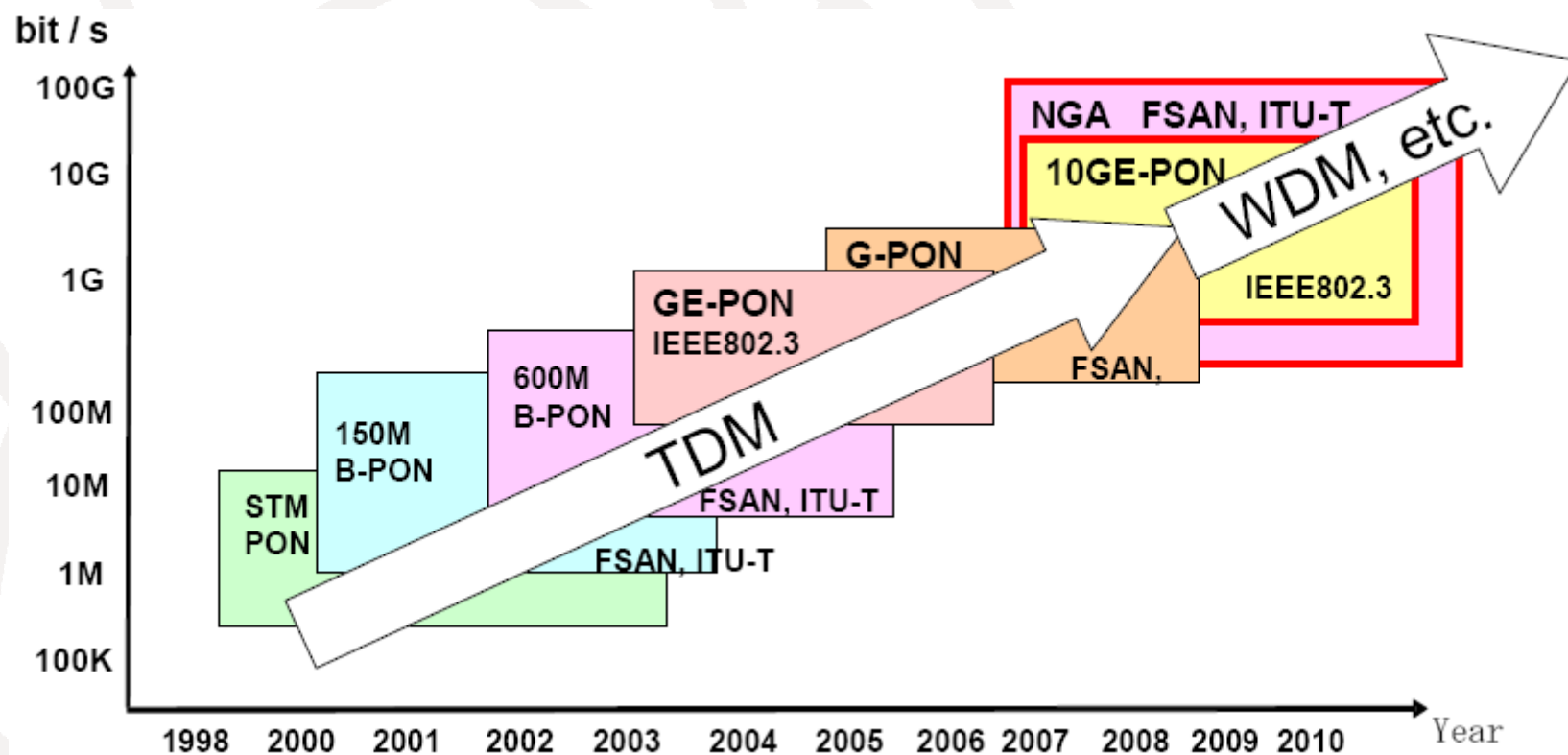
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Outline

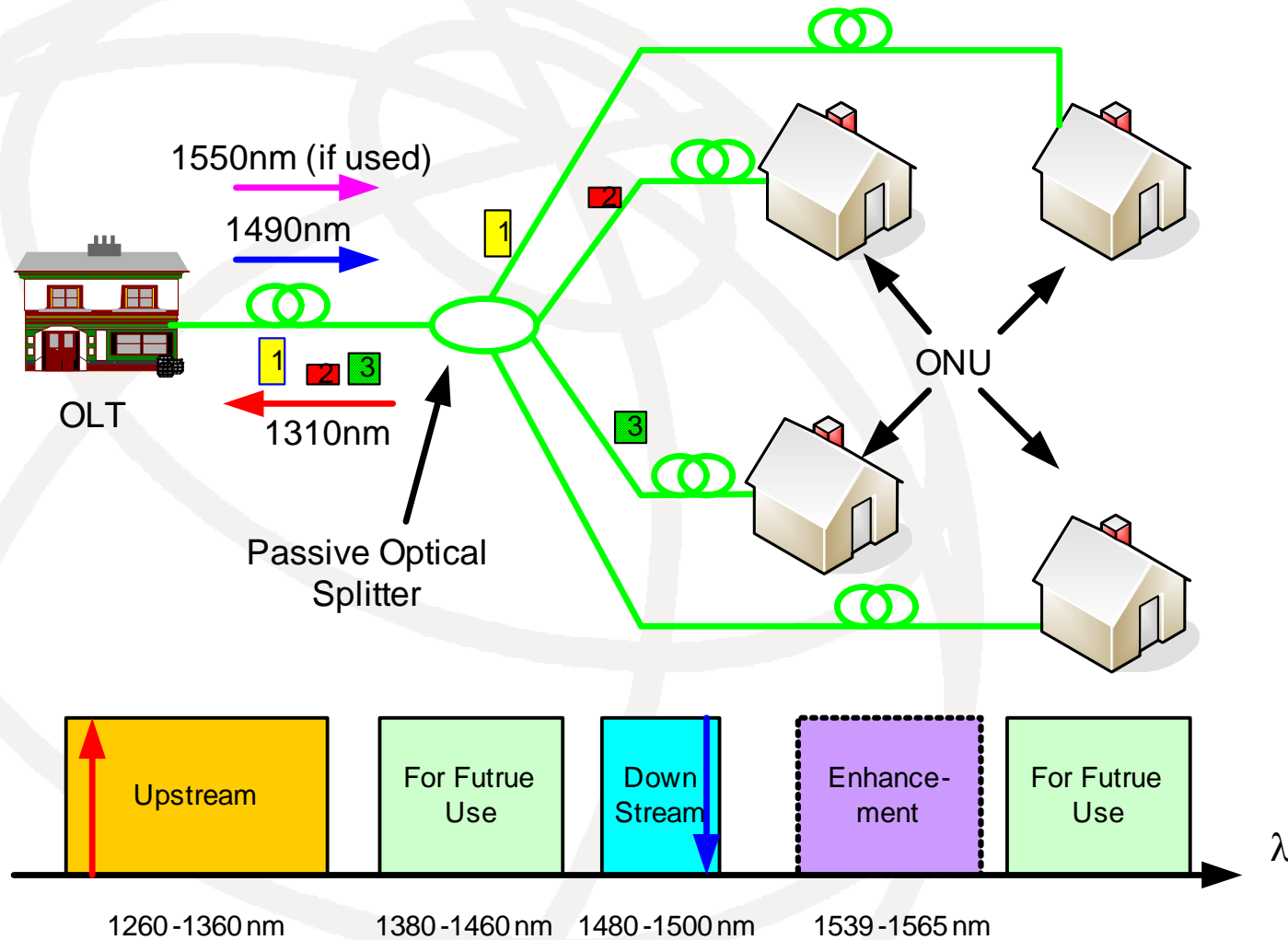
- Introduction
- Key Components in OAN
- Conventional Transceiver Technologies
- Challenges in 10GPON
- Future Trends and Optical Integration
- Summary

Optical Access Network Trends

- Higher bandwidth/capacity technologies are required for HDTV, IPTV, VOD, PVR, digital home, etc.

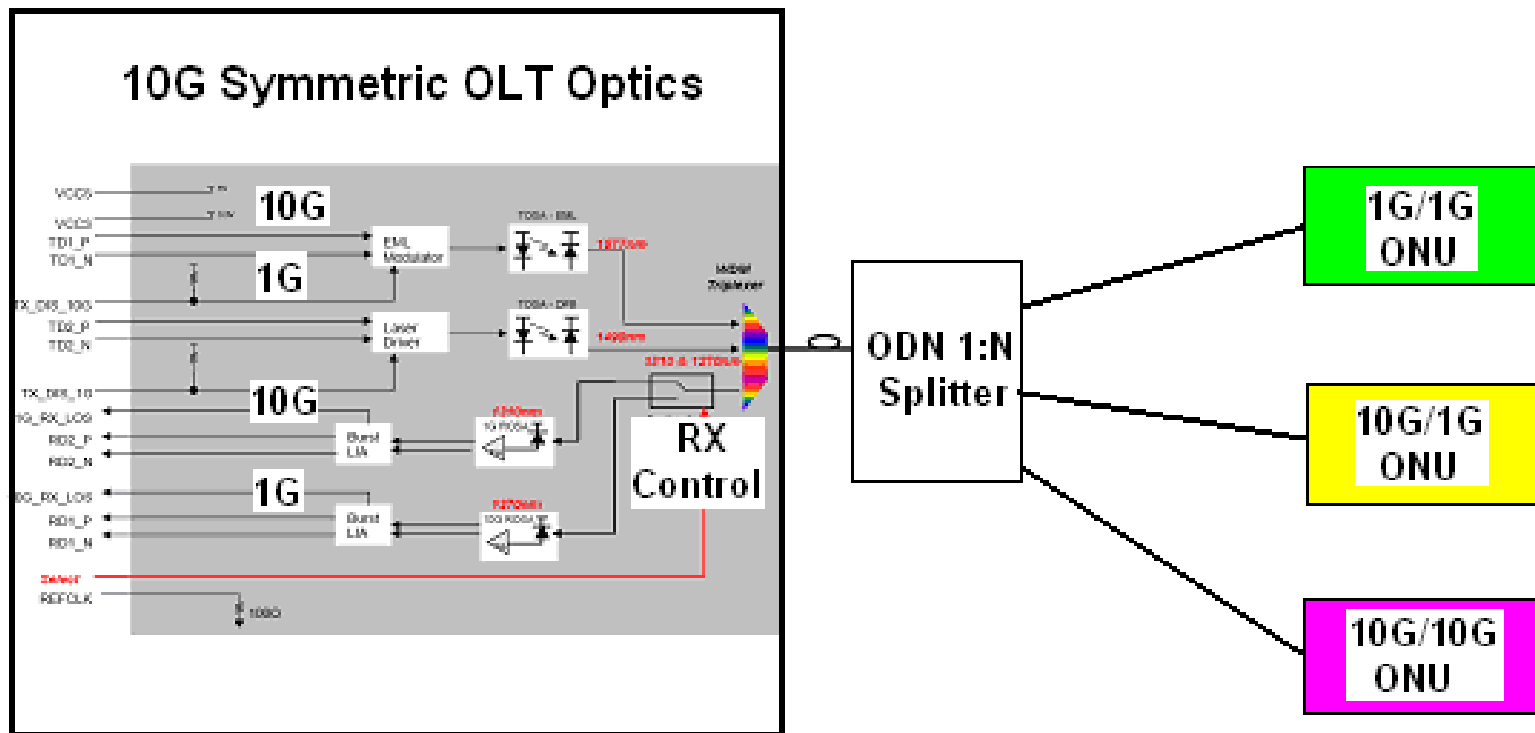


Passive Optical Network Structure



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10GEPON Quadplexer Structure

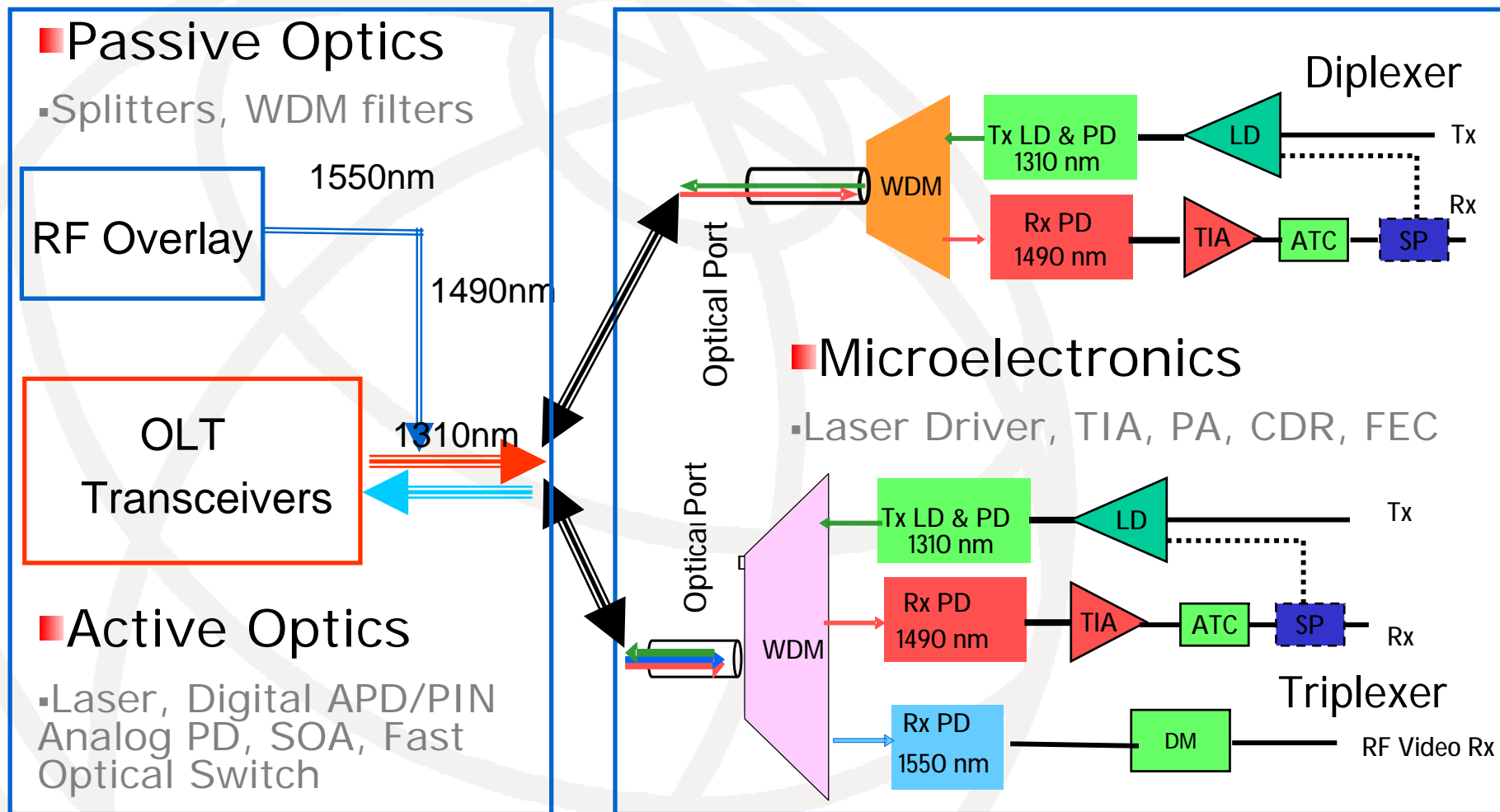


- 10GEPON and 1GEPON must be able to coexist in the existing fiber distribution network

EPON/GPON/10GEPON Review

	EPON		GPON		10GEPON
	PX-10	PX-20	Class B+	Class C+	PR-30
Link Budget	23dB	26dB	28/30dB	32/33dB	29dB
Data rate	1.25G	1.25G	2.5G/1.25G	2.5G/1.25G	10.3G
TX Laser	FP/DFB	DFB	DFB	H DFB	H EML H DML
RX PD/TIA	PIN/TIA	PIN/TIA	APD/TIA	H Sen. APD/TIA	APD+ TIA(S)+ FEC
Driver	Discrete/Integrated		Discrete	Discrete	Discrete
PA			Discrete	Discrete	Discrete
Cost	Low	Medium Low	High	High+ (OLT)	High++++ (ONU/OLT)

Key Components in the OAN



Key Issues in EPON/GPON Transceiver

■ Microelectronics

- Burst mode, short response time for detection and threshold adjustment
- Large dynamic range
- High sensitivity for small signal detection
- Relative high speed, up to 2.5Gbit/s
- Intelligence (e.g., FEC, EDC, Monitoring, etc.)

■ Active Optics

- Transmit laser diodes (high power, narrow spectral width, wide temperature, low noise, high speed, etc.)
- Receive photo diodes (high sensitivity, high linearity, high SNR, etc.)

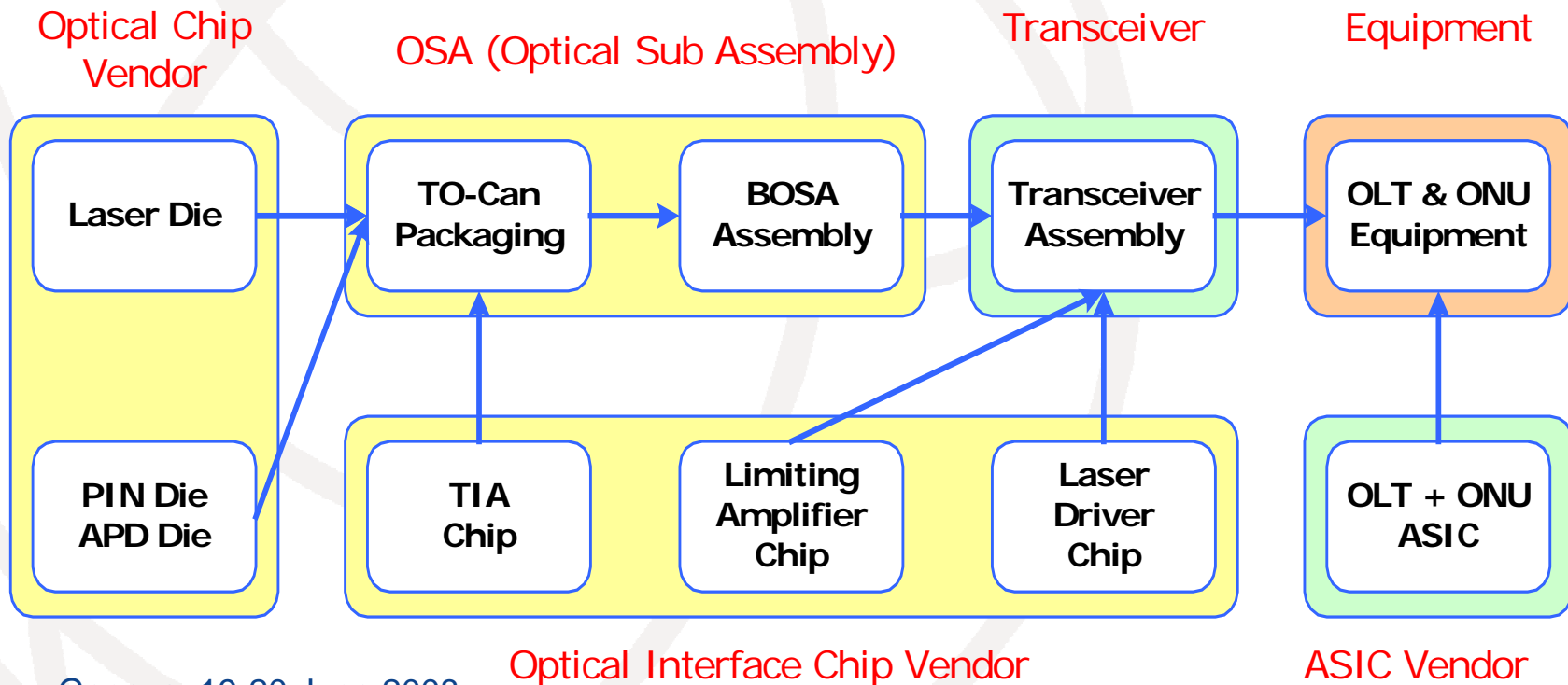
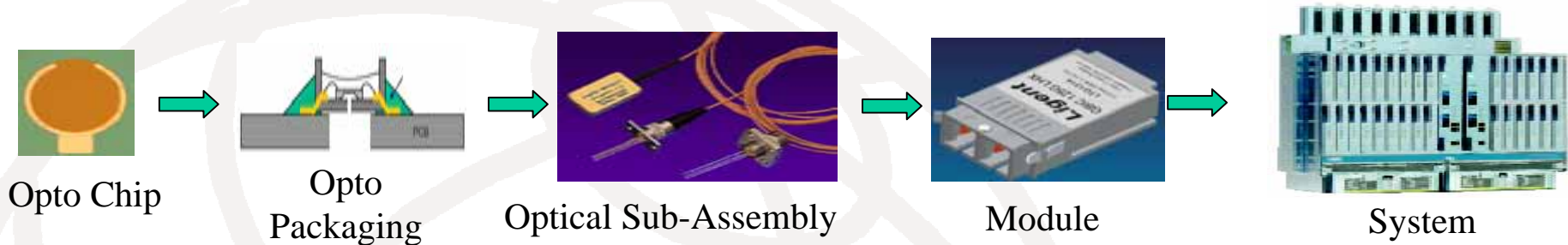
■ Passive Optics

- Low loss
- Low polarization dependence
- Low temperature dependence

■ Operating Temperature Range and Power Consumption

Low Cost, High Performance, and High Volume

FTTH Equipment Value Chain



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Conventional Transceiver Technologies

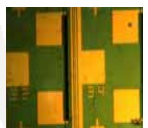
- Complex, robust, improving, and yet reaching limit?

- Discrete chips for LD, PD, lens, etc.
- Stand-alone TO-cans for TX & RX
- TX, RX and bidirectional optical sub-assemblies based on coaxial-packages
- Separate integrated MICs for analog and digital functions
- Manual module assembly and testing

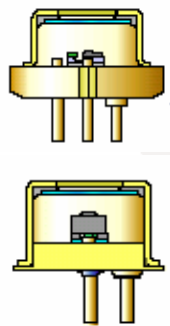
MIC Chip



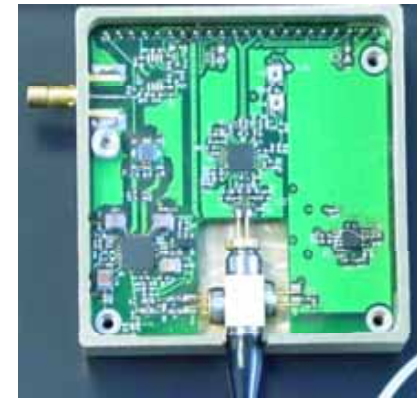
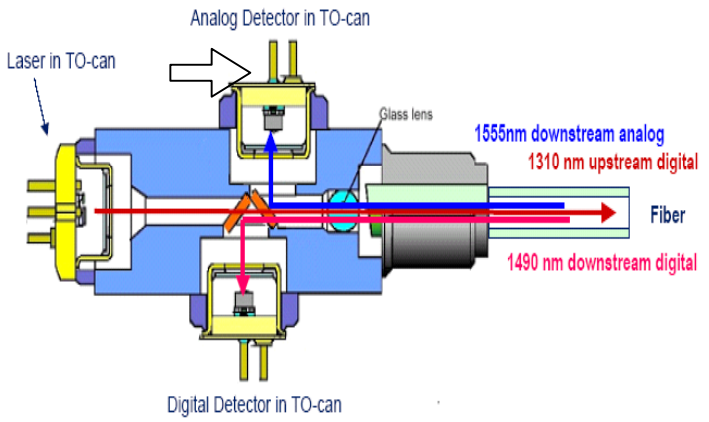
Module



Laser in TO-can



Detector in TO-can



↓
Capital intensive,
Automated fab,
Manual processing

↓
Capital intensive,
Automated assembly,
Manual test

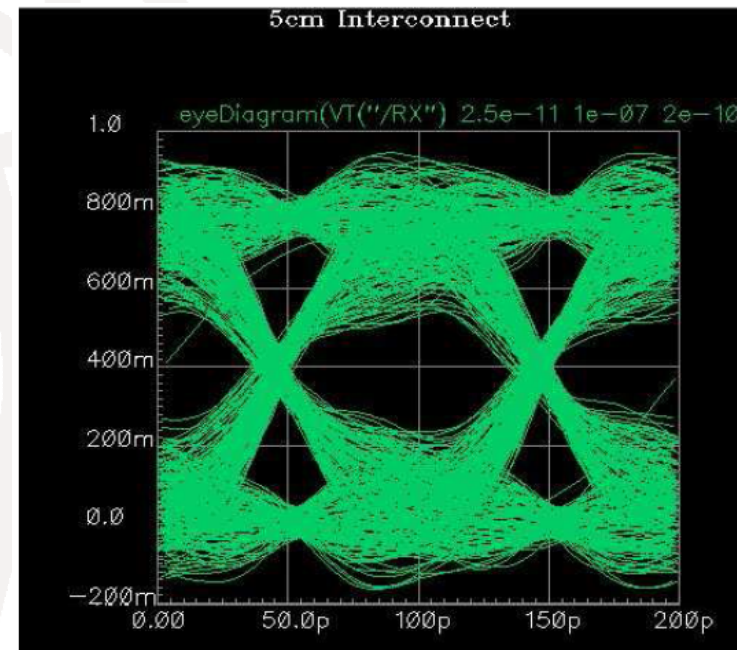
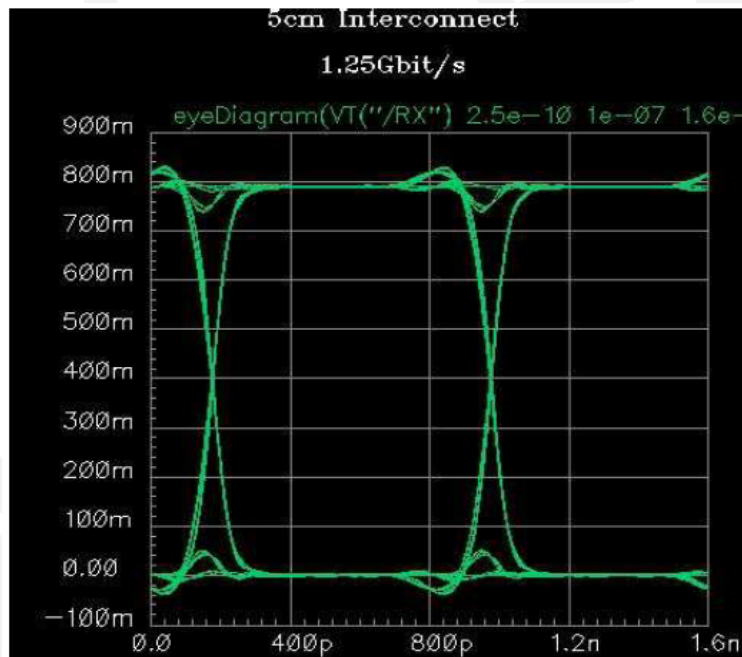
↓
Labor intensive,
Manual assembly,
Manual test

↓
Labor intensive,
Manual assembly,
Manual test

Availability of 10GPON Components

- Now 10GE CM transmission technologies and 1G/2G BM technologies are mature
- Challenges in 10GEPON BM components
 - ✓ Special 10G lasers to meet the IEEE802.3av requirements
 - 1577nm high power 10G EML laser for OLT
 - Low cost 1270nm 10G DML laser
 - ✓ 10G burst mode drivers
 - ✓ 10G/1G selective burst mode TIA and post amplifier
 - ✓ 10G burst mode CDR and signal conditioner

Problem for 10G Eye Pattern



3av_0804_benamram_2

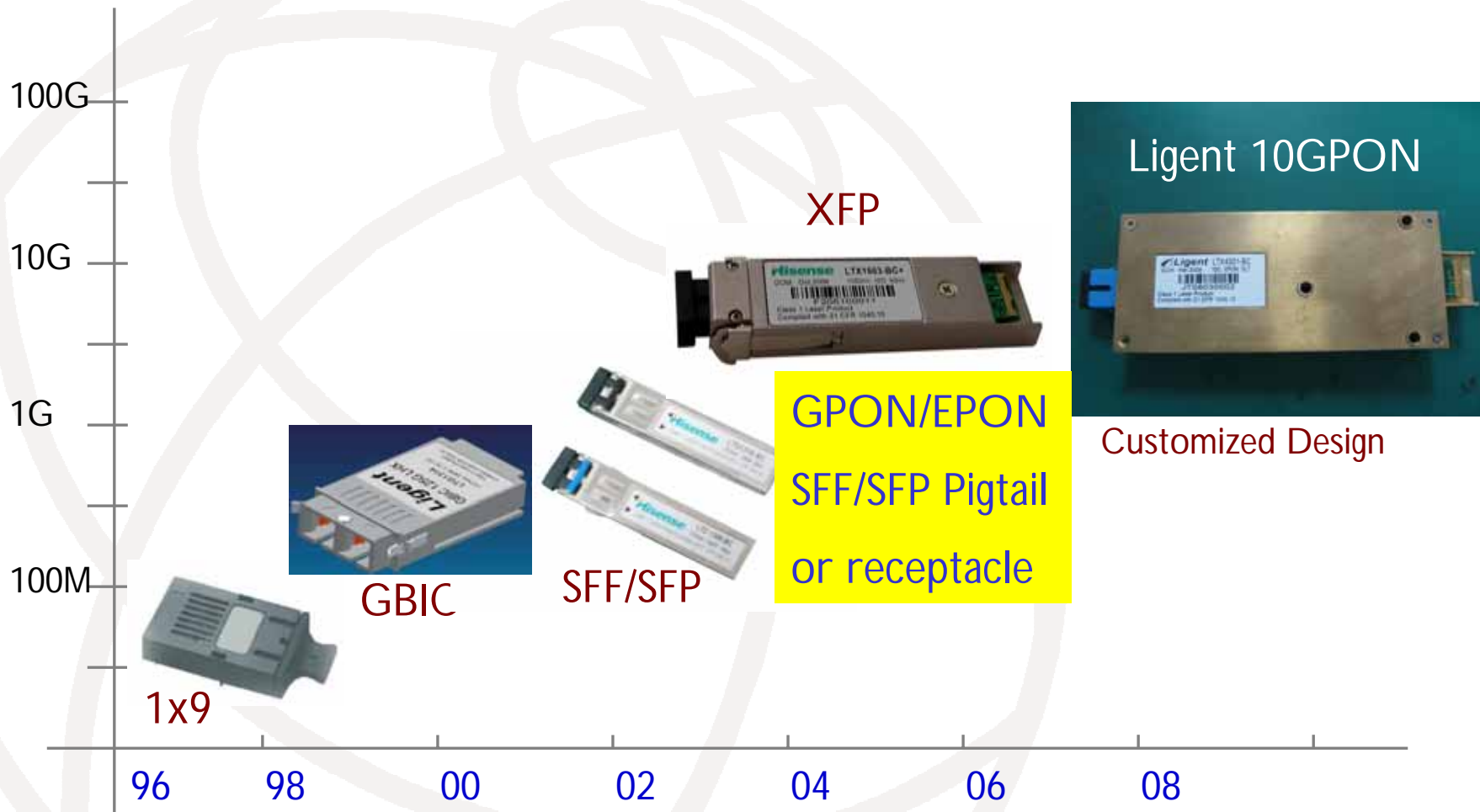
- 10G signal is much noisy
- Electrical, Optical, Test Equipment

Challenges in 10GPON

- Signal degradation at 10G
- Link budget – 29dB
- TX power – high
- RX sensitivity – high
- BM 1G/10G switching
- OSA - Integration
- Cost - low

High TX Power, High RX Sensitivity, Price

Optical Module Packaging

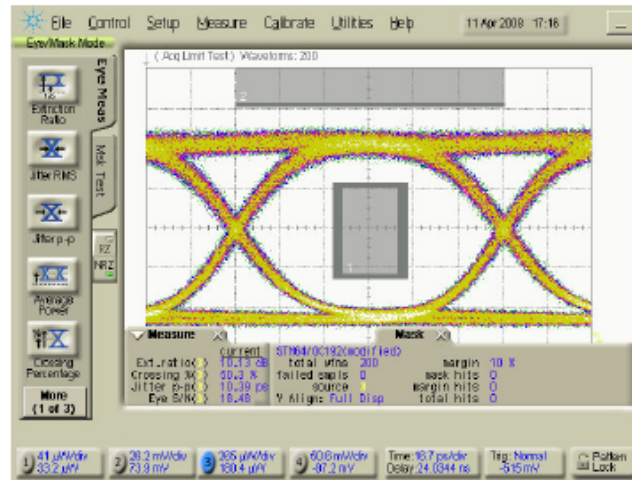


Small, Pluggable, High Density, Low Power

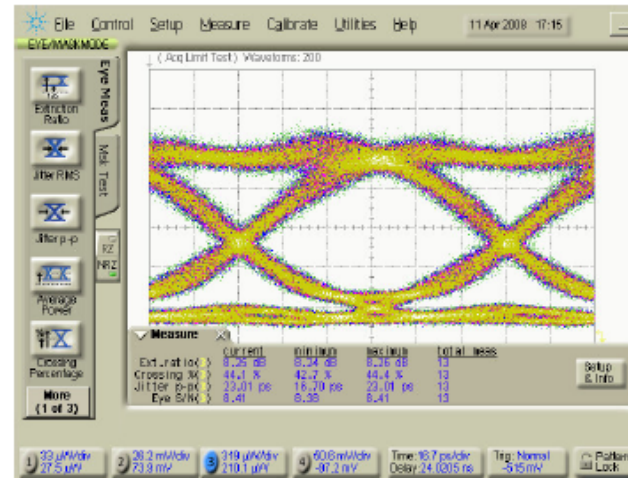
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Progress on the 10GEPON Laser

Back to back (with filter)

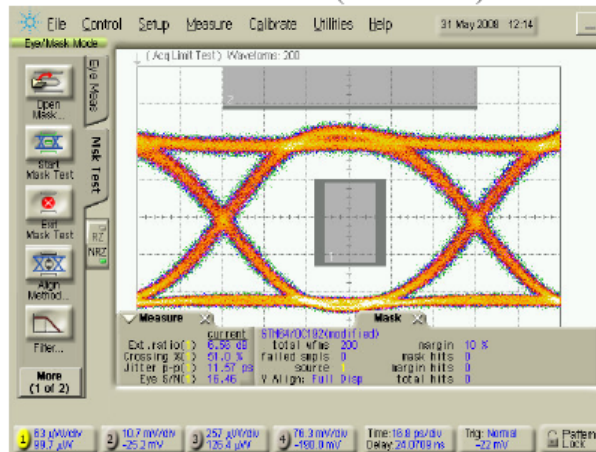


After 50km SMF transmission



Pave = 5.06dBm, WL=1577.655nm, Rext = 10.34dB, Dp=1.03dB (50km)

Back to back (with filter)

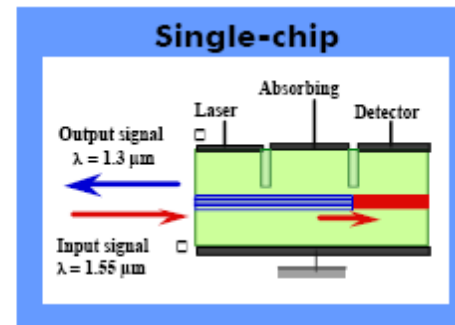
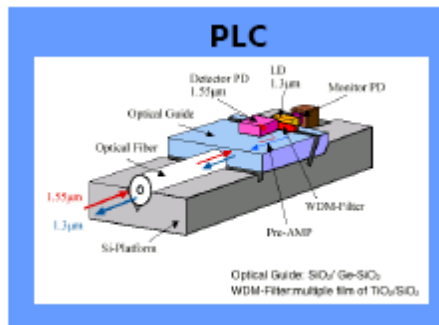
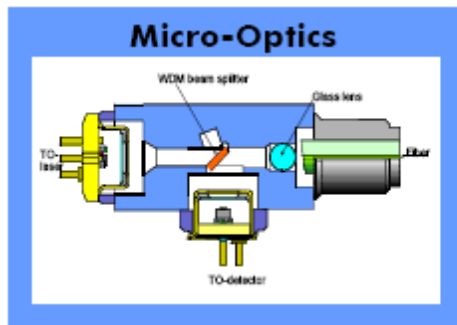
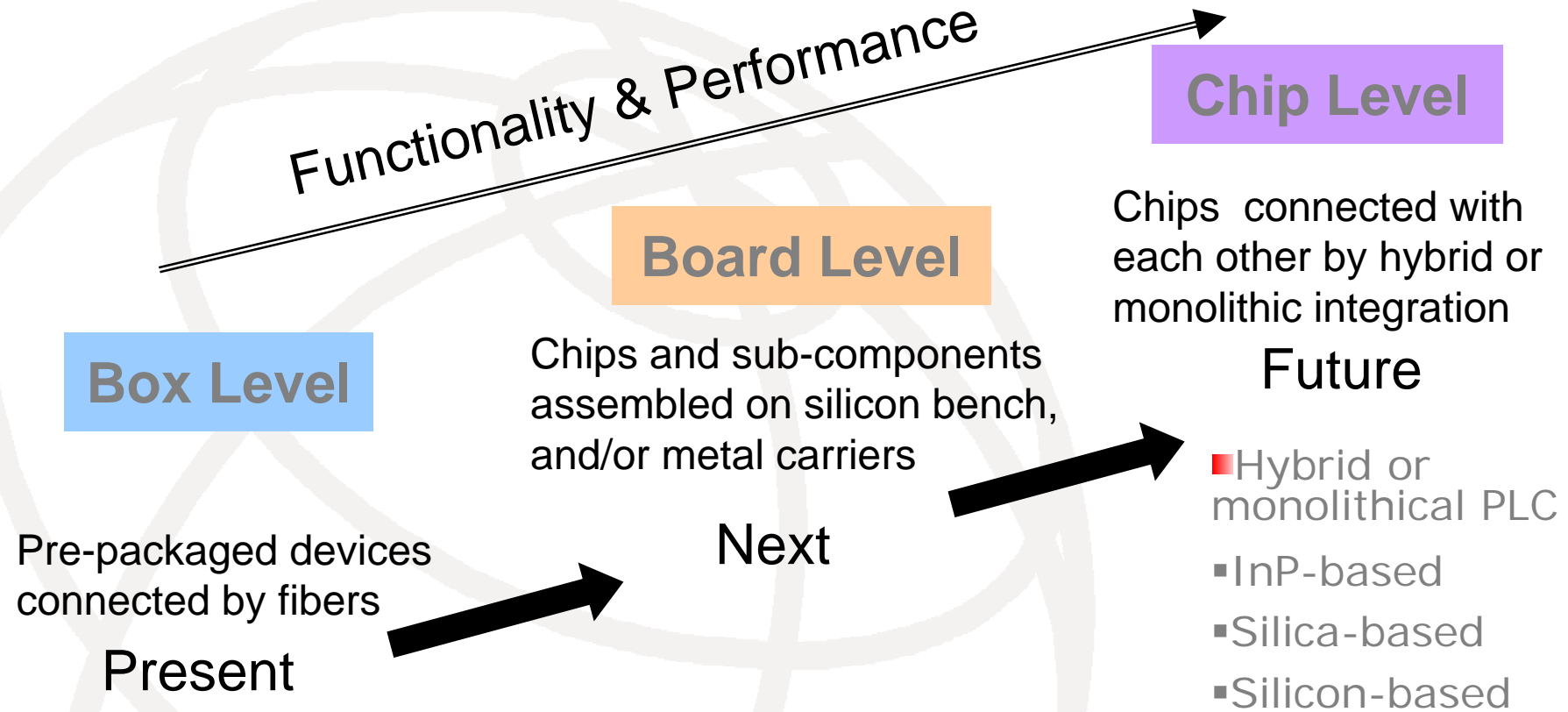


Pave = 5.05dBm, WL=1275nm, Rext = 6.56dB

Eudyna Devices,
06.02.2008

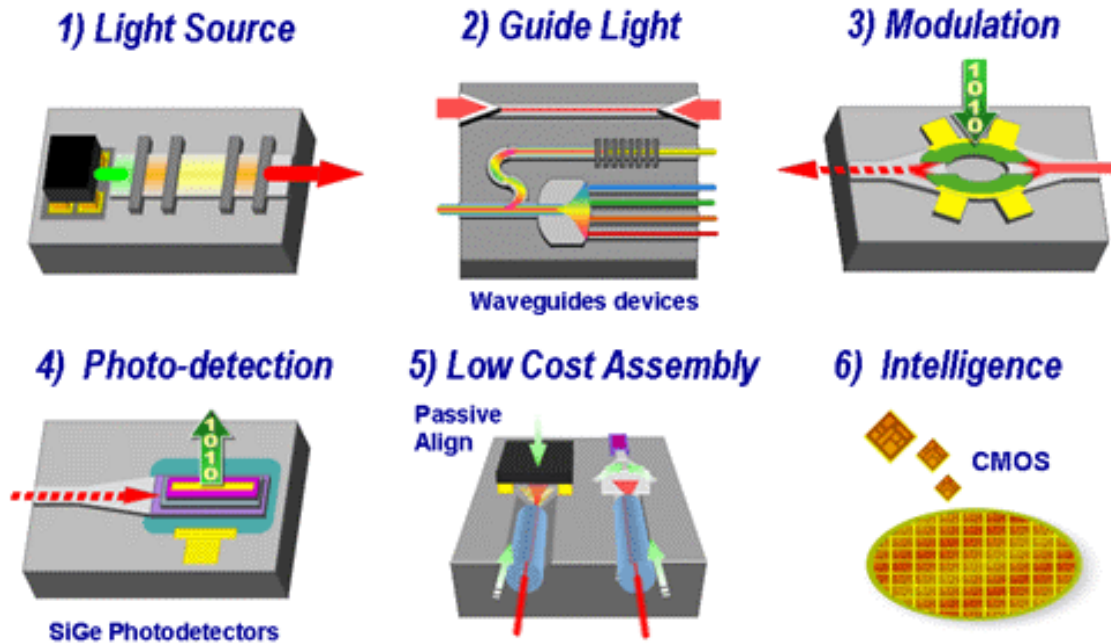
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Integration Platform Technologies



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Basic Building Blocks for PICs



• Packaging

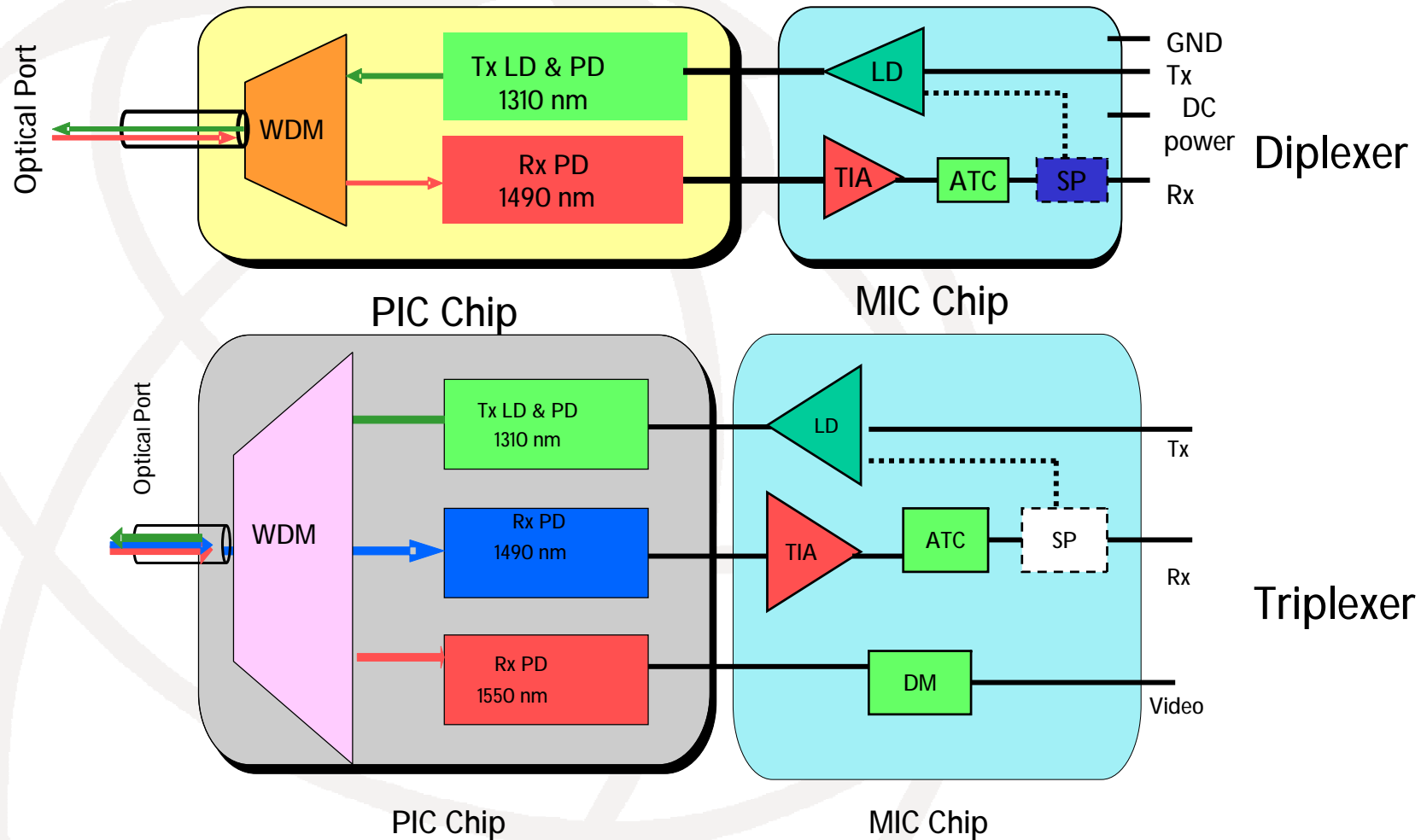
Challenges for Optical Integration

- Design and Fabrication
 - Multi-Functionality
 - Complexity
 - Redundancy
- Yield
 - Wafer uniformity
 - Coating
 - testing
- Packaging
 - Coupling to Fibers
 - Electrical Control
 - Thermal Management
 - Hermetic issue
 - **Low cost assembly**

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The Dream Device:

Integrated Optical Transceivers based on Two-Chips



W.P.Huang, OSA Optics Express, Vol. 14, 2006

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Summary

- The design and manufacturing of optical module in the access networks follows a process from discrete components to optical sub-assemblies and microelectronic chips, to module assembly and test
- The conventional transceiver technologies based on discrete optoelectronic chips and coaxial packaging are still the key enabler and continue to improve
- The emerging technologies based on planar packaging, hybrid/monolithic optical integration are under development and will have significant (not immediate) impact on the cost and performance
- The WDM, and other approaches are necessary for next generation access network beyond the 10Gbps.